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Aerosol Spray Pyrolysis Synthesis of CZTS Nanostructures for Photovoltaic Applications

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Author
Exarhos, Stephen

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Aerosol Spray Pyrolysis Synthesis of CZTS Nanostructures for Photovoltaic Applications

A Thesis submitted in partial satisfaction of the requirements for the degree of

Master of Science in
Mechanical Engineering

by
Stephen Exarhos
August 2015

Thesis Committee:
Dr. Lorenzo Mangolini, Chairperson
Dr. Marko Princevac
Dr. Sandeep Kumar
The Thesis of Stephen Exarhos is approved:

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___________________________________________

Committee Chairperson

University of California, Riverside
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ABSTRACT OF THE THESIS

Aerosol Spray Pyrolysis Synthesis of CZTS Nanostructures
for Photovoltaic Applications

by

Stephen Exarhos

Master of Science, Graduate Program in Mechanical Engineering
University of California, Riverside, August 2015
Dr. Lorenzo Mangolini, Chairperson

As harmful effects caused by the extraction, purification, and combustion of natural resources for energy generation become more clearly understood, the need for economically competitive renewable energy becomes more desirable. Solar energy-generation is a technologically feasible method, though its primary drawback is cost. Traditional single-crystal silicon-based photovoltaics are too expensive to compete with nonrenewable energy generation, while alternative materials such as cadmium telluride and copper-indium-gallium-selenide contain expensive and unsustainable elements, while cadmium is a known carcinogen. Copper-zinc-tin-sulfide (CZTS) is another alternative material, though the technology is not yet advanced enough to have reached the market.

The work presented is a study of the viability of synthesizing CZTS nanostructures using aerosol spray pyrolysis in an inexpensive, environmentally friendly, and industry-scalable way. We aerosolize a precursor solution with dissolved copper, zinc, and tin compounds and pass the droplets through a furnace, where the precursors
dissolve and thermally form CZTS structures. Using this method, we can generate thin films — by placing a substrate within the furnace — and nanoparticles. While stoichiometric CZTS seems to be formed consistently, the films grown tend to be inhomogeneous in composition and morphologically unstable, yielding an inefficient material for two-dimensional photovoltaics. Nanoparticle synthesis seems to be the more appropriate application of spray pyrolysis with this material system. We have shown the ability to control the composition and doping of CZTS nanoparticles, and preliminary efforts in coating and sintering the nanoparticles into crystalline films are promising.
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Chapter 1: Introduction/Motivation

1.1: A Background on Photovoltaics

The ability to harness the sun’s energy incident on Earth’s surface has long been touted as a large-scale electricity source of the future. The drawback thus far, though, has been cost-effectiveness. As limitations and harmful effects on burning nonrenewable resources as fuel have become more and more well documented in the past half-century, photovoltaic (PV) research has garnered significant interest in the international community, among other renewable technologies. The technology currently exists to harness solar energy, but it is not economically or politically tenable to implement large-scale solar power infrastructure. Hence, much work is currently focused on decreasing the cost of PV module fabrication, installation, and maintenance. On the cell fabrication side, a large focus is placed on optimizing alternative and inexpensive light-absorbing materials that can be produced via inexpensive and scalable processes.

French physicist Edward Becquerel is credited with the discovery of the PV effect in the mid-19th century, which, in layman’s terms, is observed when a material absorbs a photon with a certain energy to create a pair of excitons, or positively (holes) and negatively (electrons) oriented charge carriers. It took nearly a century for Becquerel’s PV effect to be applied as an effective PV cell due to the difficulty of collecting the excitons generated by photo-absorption.

Bell Labs made the major breakthrough in 1954, when Chapin, Fuller, and Pearson demonstrated the first practical solar cell, based on single-crystal silicon as the
Chapin observed that a p-n semiconductor junction will create an electric field to force the exciton pair in opposite directions [1]. This counteracts radiative exciton recombination, the statistically more probable event, making it possible to collect the opposite charges to create a potential difference across a resistive load. The simplified schematic of the p-n junction-driven PV is seen in Fig. 1.1.1. Chapin’s work on silicon-based p-n junction PVs has been steadily optimized since 1954, and today the latest iterations of this type of PV are nearing maximum theoretical efficiency.

Alternative material systems have also been studied and gradually optimized to account for the high material and processing costs associated with generating the single-
crystal silicon layer in the cell schematic in Fig. 1.1.1. Yet the cost-per-Watt of power generated still makes solar energy impractical as part of a large-scale infrastructure.

Today, the effort to improve PV technology continues, with the notion of “grid parity” limiting the widespread use of PVs in the United States [2]. In essence, the consensus is that PVs will not be widespread until it is less expensive to fabricate, implement, and maintain such devices than to purchase mass-produced power generated from nonrenewable sources — like natural gas, coal, oil, or others.

Figure 1.1.2: (From [3]) a) Shows past and projected percentages of energy consumption by fuel type from 1980-2040 in quadrillion BTU. b) Shows past and projected renewable electricity generation by fuel type from 2000-2040 in billion kilowatt hours.
Based on recent trends and public policy, the Department of Energy’s annual energy outlook for the year 2015 [3] projects that domestic energy generated by renewable fuels will continue to expand to take the place of domestic nonrenewable-based fuels like petroleum and coal (fig. 1.1.2a). Energy generation from renewable sources is projected to grow at 1.5% annually, more than any other fuel source [3]. Further, domestic solar electricity generation is projected to grow more quickly than any other renewable source at 5.5% annually, and is expected to provide about 10% of all domestic electricity generated by renewable sources in 2040 [3] (fig. 1.1.2b).

In the past few decades, there has been an ongoing search within the PV-research field for new materials and cell architectures that might circumvent the drawbacks to using silicon-based cells — namely that the most efficient single-crystal silicon-based PVs require high production and high materials cost. Thin film PVs — cells based on thin film semiconductors as opposed to bulk, necessary with single-crystal silicon cells — have been well studied utilizing different photo-absorbing materials.

Figure 1.1.3: (From [6]) Shows content and price of elements commonly used in different thin film PV absorber layers.
Copper-indium-gallium-selenide (CIGS) and cadmium telluride (CdTe) have both been extensively researched, and have been improved to be efficient enough to sell publicly via startup companies like First Solar (CdTe) [4] or Solar Frontier (CIGS) [5]. These materials, however, have significant drawbacks pertaining to mass market sustainability and environmental impact. Indium, in particular, is undesirable to use in a mass market product due to its scarcity on earth and its subsequent high cost (fig. 1.1.3), making this technology unsustainable for a large market [6]. Cadmium is a known human carcinogen, making its widespread commercial use undesirable due to possible negative health and environmental effects.

Relatively recently, in the past 25 years, copper-zinc-tin-sulfide — Cu$_2$ZnSnS$_4$ (CZTS) — has been investigated as a thin film photo-absorber for use in PV devices. This material is

![Figure 1.1.4: (From [8]) Shows chalcopyrite CIGS crystal structure (a) with different CZTS crystal structures (b, c, d).]
desirable due to the component elements’ low-cost and Earth-abundance (fig. 1.1.3).

CZTS typically has a kesterite crystal structure which resembles the chalcopyrite structure of CIGS, though it can also be found as stannite (which only differs from kesterite in placement of copper and zinc atoms) or as wurtzite. Chen et al calculate the kesterite structure to be the most thermodynamically stable of the three crystal structures [7]. Fig. 1.1.4 shows the orientations of the three CZTS crystal structures with the chalcopyrite CIGS crystal structure. The band gap of CZTS is between 1-1.5 eV, and the material has an absorption coefficient on the order of $10^4$, both desirable characteristics for use as a photo-absorber in a PV [8]. The primary advantage of using CZTS is that it offsets the drawbacks of silicon, CIGS, and CdTe technologies. Copper, zinc, tin, and sulfur are all relatively inexpensive, earth abundant, and environmentally friendly.

1.2: Thesis Direction

Presented here is our work investigating the viability of forming CZTS nanostructures and thin films by aerosol spray pyrolysis — an inexpensive and scalable technique — from metal-diethyldithiocarbamate precursors. The effect of this work is intended to prove this to be an alternative method of synthesizing high-quality CZTS thin films for use in highly efficient PV cells, while also being easily implemented into commercial-scale production.
There is herein much discussion of the application of CZTS as a photo-absorber layer in PVs, mainly in Chapter 2, though our work itself is to this point only developed as far as free-standing material synthesis and characterization.
1.3: References


Chapter 2: Literature Review

2.1: Notable Terms and Quantities

There are several terms and quantities that are used to describe the efficacy of PVs, the most notable of which are open circuit voltage ($V_{OC}$), short circuit current ($J_{SC}$), fill factor (FF), and photo-conversion efficiency ($\eta$). $V_{OC}$ is defined as the potential difference generated by a PV across an effectively infinite load between the positive and negative charge collection terminals. $J_{SC}$ is the electrical current flowing through the circuit when the load is effectively zero. There is an absolute extreme at which the PV will supply the most power, given by $P_m$ or equivalently $I_m \times V_m$. This allows the definition of FF as

$$FF = \frac{I_m \times V_m}{I_{SC} \times V_{OC}}$$  

Eq. 2.1.1

and $\eta$ as

$$\eta = \frac{P_m}{P_L}$$  

Eq. 2.1.2

where $P_L$ is the power of the light incident on the PV. $P_L$ is generally simulated in vitro [1].

For discussion in literature, it is globally accepted that PVs be characterized under the Standard Test Conditions: 25 °C under Air Mass 1.5 spectrum illumination with an incident power density of 100 mW/cm² [1].
2.2: Current CZTS Benchmarks

The current champion CZTS cell is presented by Fukano et al in [3]. The record efficiency was published to be $8.5\% \pm 0.2\%$ for a cell of 0.2382 cm$^2$. The $V_{OC}$ is listed as 708 mV and the $J_{SC}$ is listed as 16.83 mA/cm$^2$, while the FF is 70.9% [2, 3]. To give perspective, the current champion CIGS cell has $\eta$ listed as $21.7\% \pm 0.7\%$. The $V_{OC}$ is comparable, as the CIGS cell has $V_{OC}$ as 796.3 mV, but the $J_{SC}$ of the CIGS cell is vastly superior at 36.59 mA/cm$^2$ and the FF is improved to 79.3% [2, 4].

There has been extensive work done optimizing CZTS PVs by introducing selenium replacement defects in place of sulfur atoms in the kesterite lattice, with the new material called CZTSSe ($\text{Cu}_2\text{ZnSn(S}_x\text{Se}_{1-x})_4$). With this material system, a cell has been produced by Wang et al with $\eta$ listed as $12.6\% \pm 0.3\%$, with improved $J_{SC}$ of 35.21 mA/cm$^2$ but diminished $V_{OC}$ of 513.4 mV [2, 5]. While this is an encouraging improvement in photo-conversion efficiency, the material system will be disregarded in this work due to the inclusion of the rare and expensive element, selenium (see fig. 1.1.3).

In order for CZTS to be commercialized viably, it is generally accepted that the \textit{in vitro} photo-conversion efficiency needs to be boosted to $\sim 17\text{-}18\%$.

2.3: Ways to Improve CZTS-Based PV Efficiency

Due to the similarities between the CIGS and the CZTS material systems, it is logical to attempt to improve CZTS-based PVs in similar manners as have already proven effective in the improvement of CIGS-based PVs to beyond 20% efficient.
In 2013, a meeting of experts in the field was convened to identify critical steps toward improving CZTS as a thin film PV material [6]. The V_{OC} deficit (given by the difference between the the band gap voltage — E_g/q — and the V_{OC}) in well-performing CIGS-based PVs is ~500 mV, while in the best CZTSSe devices the deficit is higher than 650 mV. From section 2.2, the benchmark CZTS device in [3] has a V_{OC} of 708 mV, which still yields a V_{OC} deficit of greater than 750 mV.

Quoting from [6]:

“Three key areas were identified to address this problem, as listed here in rough order of priority: (1) defect characterization and passivation, (2) phase stability and processing control, and (3) interface optimization.”

Further from [6], defects in the CZTS layer cause the semiconducting properties of the material — primarily the band gap — to be nonuniform through the bulk material, leading to additional impedance affecting the generated excitons. The high V_{OC} loss is attributed to charge recombination centers, focused at bulk defect sites as well as grain boundaries and interfaces. The formation and control of these defects is not well understood at this point. With further understanding will come the ability to promote beneficial defects and to diminish detrimental ones in the synthesis of the CZTS absorber layer. The pn-junction also must be optimized in order to reduce interfacial exciton recombination.

Current work on improving the CZTS absorber layer focuses generally on improving the material stoichiometry [7-12] and crystallinity [13-17] within existing
synthesis processes. Further efforts are focused on improving the pn-junction consisting of the CZTS and a thin n-type layer [18-20]. In short, it has been concluded that the ideal stoichiometry is slightly copper-poor and zinc-rich, that the presence of alkali metal defects in CZTS greatly aid crystal growth during annealing, and that ZnS is likely the ideal n-type material to pair with CZTS. Further work must be done to support these conclusions more solidly, though this is generally consensus in the field as observed at the 2015 MRS Spring Meeting.

2.4: Material Synthesis

There are many different methods that have been used to generate CZTS or CZTSSe. The previously-mentioned CZTSSe benchmark was set in 2013 for a cell based on a CZTSSe layer grown using a hydrazine pure-solution approach [5]. The benchmark CZTS cell was made by sputtering ZnS/Sn/Cu/ZnS layers then annealing in a sulfur-rich atmosphere [3]. Further methods that have been used to synthesize CZTS layers for PVs are evaporation [21-32], sputtering [33-45], electrodeposition [46-53], sol-gel based deposition [54-62], pulsed laser deposition [63-68], screen printing [69-70], chemical bath deposition [71-75], nanoparticle based sintering [76-89], and aerosol spray pyrolysis [90-98].

Of these synthesis methods, evaporation, sputtering, and electrodeposition have generally yielded the highest efficiency devices. Other methods are primarily intended as more cost-effective or scalable alternatives.
Aerosol spray pyrolysis will be discussed further in section 2.5. Nanoparticle synthesis and sintering will be discussed further in sections 2.6 and 2.7.

**Evaporation:**

Evaporation is a commonly used process to synthesize metallic or semiconducting thin films. The target material, in liquid or more typically solid phase, is evaporated by a concentrated electron beam, directed by Coulombic force, and directed onto a substrate [99] (fig. 2.4.1). Typically, evaporation of the target will be incited by an electron beam, but it can also be achieved thermally. This process can be done with an individual target, or multiple targets can be used simultaneously. For example, a cuprous sulfide thin film can be formed by co-evaporating copper and sulfur targets.

There are two common methods by which evaporation is used to synthesize CZTS. Katagiri et al pioneered the method by evaporating separate copper, zinc, and tin layers onto a heated molybdenum-coated soda lime glass substrate, then thermally annealing in an $\text{N}_2 + \text{H}_2\text{S}$ environment [21, 22]. The material was characterized to be stannite CZTS. The stoichiometry of the material was governed by the relative thickness of the three metallic layers.
Other groups have added sulfur in the evaporation process, either via the replacement of the zinc target with a zinc sulfide target [23-26, 31], or the addition of a sulfur target to the three elemental targets [27].

Some of the most efficient CZTS-based PVs to have been reported have all been fabricated with a co-evaporated CZTS layer with an added thermal annealing process.

*Sputtering:*

Sputtering is also a commonly known process. It is similar to e-beam evaporation, but the target material is eroded away by a gaseous ion plasma, typically made from an inert carrier gas like argon, instead of an electron beam. Neutral particles of the target material ejected from the target then nucleate and form a thin film on the substrate surface [100] (fig. 2.4.2). Similar to evaporation, this process can use multiple targets to form alloy thin films.

Sputtered synthesis of polycrystalline stannite CZTS was first reported by Ito and Nakazawa in 1988 [33]. They reported an improved quality film with decreasing resistivity as substrate temperature during film growth was increased. The conclusion drawn was that CZTS is a suitable absorber layer for a PV due to its high absorption coefficient and its direct band gap.
Again similar to evaporation, there has been work reported as having synthesized CZTS via thermal annealing of a sputtered stack of copper, zinc, and tin metals [35, 36, 40, 41, 44], as well as work reporting the sputtering of binary sulfide targets — most commonly in the form of tin sulfide and zinc sulfide with elemental copper [37-39, 42, 43, 45].

Sputtering deposition creates films of a similar quality to evaporation, so it is not surprising that sputtering-deposited CZTS-based PVs have similarly impressive efficiencies to those synthesized via evaporation, including the current benchmark in [3].

**Electrodeposition:**

Electrodeposition uses precursor materials dissolved in an electrolyte to complete a circuit across two electrodes, with the current flowing between the electrodes through the electrolyte causing the dissociation of the precursors and deposition onto the working electrode [101] (fig. 2.4.3). Electrodeposition is more dependent on precursor materials than processing conditions, as opposed to the previously discussed vapor deposition processes. The process is presented as more inexpensive and scalable than vacuum-based vapor deposition processes.

Figure 2.4.3: General schematic for an electrodeposition setup.
To make CZTS, there are a variety of precursors that can be used. Scragg et al demonstrated the synthesis of a copper-tin-zinc metal stack via electrodeposition, followed by a sulfur-vapour annealing step to make CZTS. The work used three separate deposition steps, the each using a singular copper, tin, or zinc chloride as the precursor dissolved in the electrolyte [47]. There has been further work via the same precursor chemistry in [46, 49, 51]. There has also been some study of single-step electrodeposition of CZTS by combining copper, zinc, and tin sulfates with sodium thiosulfate in the electrolytic solution in [53], as well as further single-step depositions in [47, 48, 50, 52].

Ahmed et al reported a 7.3% efficient CZTS-based PV in [46], the highest value yet reported for this sort of process, based on a thermally annealed electrodeposited three-metal stack of copper, zinc, and tin.

**Sol-Gel Deposition:**

The sol-gel deposition is fairly straightforward in concept. Precursor metal salts are dissolved in a mixture of solvent and binder, then coated onto a substrate. Thermal treatment of the coating allows for evaporation of the solvent and decomposition of the precursors. A further annealing step allows for the full conversion to a CZTS thin film [56]. This process is advantageous due to its cost-effectiveness and ability to be run at atmospheric pressure.

The biggest source of variety for CZTS synthesis from the sol-gel deposition method is the use of different precursors and solvents. The highest efficiency cell based on a CZTS layer fabricated in this fashion is outlined in [56]. Su et al used a non-aqueous
thiourea-metal-oxygen molecule as the precursor solute, which underwent thermal decomposition at a relatively low temperature to leave a more favorable material behind. Their best cell achieved an efficiency of 5.1%. More commonly used as precursor solutes are copper, zinc, and tin acetates or chlorides with or without a sulfur source added as precursor via thiourea [54, 55, 57-59, 62] ([59] used tin sulfide as the tin source).

**Pulsed Laser Deposition:**

Pulsed laser deposition (PLD) is a vacuum process similar to evaporation and sputtering. Energy is supplied to a target, typically in the form of a pellet, via a high-energy laser pulse. Material is ablated from the target in the form of ionic plasma, which then settles on a substrate within the chamber [102] (fig. 2.4.4). Targets can be elementary or alloy, allowing for deposition of either simple or complex thin films. These films still require a further annealing step after deposition.

The best device fabricated using this method has an efficiency of 3.14% [64]. The PLD deposition was achieved by ablating a target formed by mixing copper, tin, and zinc binary sulfides in adequate ratios into a solid CZTS pellet. Further work studying the PLD deposition of CZTS from a CZTS pellet has been shown in [66, 67]. Moriya pioneered this method of CZTS deposition by depositing a mixture of copper, zinc, and
tin, then annealing in a sulfur atmosphere [63, 65]. Further work has been done using zinc sulfide and copper-tin-sulfide multicomponent targets [68].

**Screen Printing:**

Screen printing deposition is very similar to sol-gel deposition. It is a solution-phase process by which CZTS particles are dispersed into a solvent at high concentration to make a thick paste. The solution is then coated by dragging the paste across a screen placed atop the substrate. The coating is then thermally treated to evaporate solvent and remove organic ligands [69].

Screen printing is well known in the PV field. It has been used in fabricating crystalline silicon PVs, which proved to be a fiscally advantageous innovation [1]. The best cell efficiency discussed in [69] was 0.49%, but the advantages — being cost-effective, scalable, well-known to industry, and relatively simplistic — of using such a process as screen printing have proven effective in PV fabrication in the past, and could prove to be so for the CZTS material system as well in the future.

**Chemical Bath Deposition:**

Chemical bath deposition (CBD) is a similar process to electrodeposition. It is another non-vacuum, conceptually simple method of thin film deposition. The process depends simply on the either chemical and/or thermal dissolution and deposition of precursors based on the solution bath chemistry and the surface of the substrate [103] (fig. 2.4.5).

![Figure 2.4.5: General schematic for a CBD setup.](image)
CBD has been used to synthesize CZTS thin films in various ways. Wangperawong \textit{et al} deposited copper, zinc, tin, and sulfur layers and annealed the samples to form CZTS [71]. Similar results have also been achieved by depositing layers of copper, zinc, and/or tin binary sulfides [73-75]. This method has not been shown to be viable relative to other low-cost non-vacuum based methods, with the highest efficiency reported for a CBD-deposited CZTS-based PV as 0.16\% [71].

2.5: Spray Pyrolysis Synthesis of CZTS Thin Films

Aerosol spray pyrolysis is a non-vacuum solution/gas phase process. In theory, it is similar to the previously discussed solution-based processes in section 2.4. Spray pyrolysis relies on the thermal decomposition of precursors in order to form a desired material. It differs, though, in the notion that the precursor solution is aerosolized via a nebulizer into micro-scale droplets before deposition to decrease the deposition speed, which theoretically allows more complete thermal equilibration to form the desired material [104] (fig. 2.5.1).

There have been several reports of using spray pyrolysis to synthesize CZTS thin films. Generally, a precursor solution containing copper, zinc, and tin chlorides or acetates plus thiourea is used, with an operating substrate temperature between 400-450
°C [90-98]. The generally universal conclusion is that the resulting film is not phase-pure, with primarily copper sulfide impurities, and further the crystallinity of the sprayed films post-annealing is poor for PV applications.

A further disadvantage of this work is the use of metal chlorides or acetates as precursors. The chlorine or oxygen present in the precursors leads to a high concentration of undesirable impurities in the sprayed film.

Aerosol spray pyrolysis is regarded as a readily scalable method for CZTS synthesis, as it is a process well known to be successful in synthesizing nanoparticles. For example the method is used to form titania nanoparticles [105], which are commonly used in pigments and cosmetics, as well as other more technological applications.

In our work, we have studied the growth of CZTS thin films by spray pyrolysis, though we use copper, zinc, and tin diethyldithiocarbamate (C$_5$H$_{10}$NS$_2$) precursors [106]. The advantage of using these precursors is the lack of chlorine or oxygen in the ligand, which lead to impurities in the film.

2.6: CZTS Nanoparticle Synthesis

A method of creating CZTS that has been steadily growing in interest in recent years is nanoparticle sintering. It is thought to be among the most cost-effective and scalable methods outlined in this document, and marked recent improvements in reported efficiencies for nanoparticle CZTS-based PVs suggest there is still room for improvement in material processing. CZTS nanoparticle-based PVs have been reported to have 3.6%
efficiency under conventional construction [84], and up to 5.02% efficiency with a novel three-dimensional architecture [82], which puts it close the the range of PVs fabricated with vacuum-processed CZTS.

There are different methods of CZTS nanoparticle synthesis that have been employed, which yield nanoparticles with different material properties. The most common method is solution-phase thermolysis [76-79, 81-89]. In this method, precursor solutes are dissolved with the help of an acidic solvent. Typically precursor solutes are basic copper, tin, and zinc chlorides or acetates plus thiourea as the sulfur source, as are used in other solution-phase processes outlined above [76, 77, 81-86, 88, 89]. Other work has used the single-source metal and sulfur precursors copper, tin, and zinc diethyldithiocarbamates (C₅H₁₀SN₂) [78, 79, 87]. The advantage to the single-source metal and sulfur precursors lies in the reduction of undesirable impurity atoms in the reactor, which are present with the use of chlorides or acetates. The solution is then combined with a hot amine solvent and thermally treated under an inert atmosphere to decompose the solutes and form CZTS nanoparticles. The resultant particles are invariably capped by organic ligands leftover from the amine solvent.

The nanoparticles synthesized in the method above are highly controllable in composition and size, both ideal for adjusting the synthesis for optimal PV performance. Once the nanoparticles are isolated, they can be dispersed into a colloidal ink, then coated on a substrate. The porous nanocrystal film must then be sintered to form large crystal grains, on the order of the thickness of the film, for the best PV characteristics [1].
The work described in this document, in Chapters 3-4, outlines a novel method of controllably forming ligand-free CZTS nanoparticles via aerosol spray pyrolysis. The method is very similar to that outlined in Section 2.5 (and fig. 2.5.1), but the substrate is removed from the thermal region and a particle collection apparatus is added beyond the thermal region to collect the synthesized nanoparticles.

2.7: CZTS Sintering/Annealing

Most of the methods of forming CZTS absorber layers for PVs listed in Sections 2.4-7 require an extra annealing/sintering step in a sulfur environment. Generally, the reason is to allow thermal equilibrium of phases and crystallinity for the film to possess the optimal PV characteristics. As discussed in Section 2.3, the two most important steps to improving CZTS as a PV absorber material is passivating and decreasing undesirable defects and improving phase stability [6].

When a metal stack or metal-alloy is deposited on a substrate, the sulfur annealing process is required to diffuse sulfur into the metal layer(s) and form crystalline CZTS. The annealing time is understandably lengthy in this case, on the scale of 8-10 hours [1], in order to allow the sulfur to fully diffuse through the film and to achieve equilibrium. With sulfur already included in the pre-annealed film, the annealing step requires much less time, now on the order of 1 hour or less [1]. In this case, the annealing step is geared towards increasing crystal grain size and phase purity. With a nanoparticle CZTS film,
the annealing step is also short and aimed at increasing crystal grain size, as the nanoparticles are already assumed to be phase pure.

The conditions of the annealing process must be optimized with the CZTS film. It has been observed that under different annealing conditions, primarily with annealing temperature and sulfur pressure varied, different material phases tend to out-diffuse from the CZTS film, primarily the binary copper sulfide and tin sulfide phases [107]. The same has been observed in annealing tin-rich and copper-rich samples in our work. Typically, the stoichiometry of the film must be compensated slightly to account for the loss of some tin and copper during annealing [1].

There are two methods of sulfur-annealing used in literature. The first requires an evacuated quartz ampoule or graphite vessel with solid sulfur placed inside with the sample ([78], for example). Upon thermal treatment, the sulfur is vaporized to provide an easily variable sulfur pressure during the anneal. The other method uses a thermal flow reactor, with the sample placed inside a thermal region feeling a flow of 1-5% \( \text{H}_2\text{S} + 95-99\% \) inert gas ([21], for example). Both methods have been demonstrated as effective in annealing and sintering CZTS films for use in PV cells.

2.8: CZTS Thin Film and Nanoparticle Characterization

As difficult as fabricating the complex quaternary CZTS is, characterizing the presence of phase-pure CZTS is equally challenging. X-ray diffraction (XRD), is the most common and straightforward method of characterizing crystalline phases in bulk or
nanostructured material, but XRD alone is not enough to adequately characterize CZTS. The diffraction peaks associated with kesterite CZTS are also common to other binary or ternary sulfide phases that can segregate from CZTS. In particular, zinc sulfide and copper-tin-sulfide give identical or effectively identical diffraction spectra, making it impossible to tell which phases might be present. Raman spectroscopy (Raman) in combination with XRD provides enough data to characterize each of these binary or ternary sulfide phases as separate from the quaternary kesterite CZTS phase [108].

Further material characterization can be performed via X-ray photoelectron spectroscopy (XPS) and energy dispersive x ray spectroscopy (EDS). These techniques make it possible to identify relative atomic proportions within a sample, as well as the presence and abundance of impurity elements relative to the CZTS material [29].

Optical characterization techniques also allow the identification of the semiconducting properties of a CZTS thin film or nanoparticles. Conducting UV/Vis/NIR spectrophotometry (photospec.) allows the measurement of the material’s absorbance across a broad spectrum. Typically PV absorbers such as CZTS are optimized to have broad absorbance across the UV and visible spectrum, correlating to the spectrum of light given off by our sun. From this data, a Tauc plot can be created, by plotting the square of the product of the material’s absorbance and the photon energy (hv) [1]. Extrapolation of the Tauc plot allows for a reasonable estimation of the materials optical band gap.
2.9: References


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Chapter 3: Experimental

3.1: Precursor Synthesis

In order to ensure consistent precursor quality, the metal-diethyldithiocarbamate precursors are formed in-house. The precursor synthesis is outlined in the supplement to [1]. In essence, sodium diethyldithiocarbamate is mixed with zinc, tin, and copper chlorides to cause an ion-replacement to form sodium chloride and metal diethyldithiocarbamate products, which are then cleaned and purified to isolate the desired material.

To form zinc diethyldithiocarbamate — Zn(dedc)₂ — (white), 9.0 g of sodium diethyldithiocarbamate (Sigma-Aldrich Corporation, St. Louis, MO) is dissolved in 150 mL of ethanol. Concurrently, 3.38 g of zinc chloride (Sigma-Aldrich Corporation, St. Louis, MO) is dissolved in 50 mL of ethanol. The sodium diethyldithiocarbamate solution is added dropwise to the zinc chloride solution under constant stirring via a burette. Upon completion of the solution combination, the product is stirred for a further ten minutes, followed by ten minutes of ultrasonication, to ensure

![Figure 3.1.1: Shows thermogravimetric analysis and decomposition of Zn(dedc)₂ (red), Sn(dedc)₄ (green), and Cu(dedc)₂ (blue) with temperature.](image-url)
completion of the ion-replacement reaction. The product is then washed in ethanol and deionized water, separated via centrifuge, and washed again until the product is washed five times. The product is then dissolved in chloroform and dried under argon flow. The synthesized Zn(dedc)₂ is fully decomposed above 334 °C (fig. 3.1.1).

To form tin diethyldithiocarbamate — Sn(dedc)₄ — (orange), 12.85 g of sodium diethyldithiocarbamate (Sigma-Aldrich Corporation, St. Louis, MO) is dissolved in 200 mL of ethanol. Concurrently, 3.0 mL of tin tetrachloride (Sigma-Aldrich Corporation, St. Louis, MO) is dissolved in 50 mL of ethanol. The sodium diethyldithiocarbamate solution is added dropwise to the tin tetrachloride solution under constant stirring via a burette. Upon completion of the solution combination, the product is stirred for a further ten minutes, followed by ten minutes of ultrasonication, to ensure completion of the ion-replacement reaction. The product is then washed in ethanol and deionized water, separated via centrifuge, and washed again until the product is washed five times. The synthesized Sn(dedc)₄ is fully decomposed above 318 °C (fig. 3.1.1).

To form copper diethyldithiocarbamate — Cu(dedc)₂ — (dark green/black), 9.0 g of sodium diethyldithiocarbamate (Sigma-Aldrich Corporation, St. Louis, MO) is dissolved in 150 mL of ethanol. Concurrently, 4.23 g of copper chloride (Sigma-Aldrich Corporation, St. Louis, MO) is dissolved in 50 mL of ethanol. The sodium diethyldithiocarbamate solution is added dropwise to the copper chloride solution under constant stirring via a burette. Upon completion of the solution combination, the product
is stirred for a further ten minutes, followed by ten minutes of ultrasonication, to ensure completion of the ion-replacement reaction. The product is then washed in ethanol and deionized water, separated via centrifuge, and washed again until the product is washed five times. The product is then dissolved in chloroform and dried under argon flow. The synthesized Cu(dedc)$_2$ is fully decomposed above 302 °C (fig. 3.1.1).

3.2: Precursor Solution Chemistry

The precursor solution used in the spray pyrolysis experiments outlined here is generally a combination of zinc, tin, and copper diethyldithiocarbamates dissolved in toluene. The amounts of the precursors must be calibrated with the apparatus in order to achieve the desired CZTS stoichiometry, as the system is not 100% efficient in converting the precursors into CZTS. This is hypothesized to be due to the complexity of crystalline CZTS, a quaternary kesterite-structured material, so the experimental conditions within the apparatus are difficult to set to the thermal conditions that are optimal to create CZTS (fig. 3.2.1).

Figure 3.2.1: (From [2]) Effective ternary CZTS phase diagram from relative ratios of Cu$_2$S, SnS$_2$, and ZnS. Stoichiometric CZTS is circled in red.
Depending on the desired powder/thin film composition, the precursor solution is concocted by dissolving 361.9 mg Zn(dedc)$_2$ (white) in 60 mL toluene, then dissolving 711.8 mg Sn(dedc)$_4$ (orange) in the Zn(dedc)$_2$ + toluene solution, then dissolving 720.2 mg Cu(dedc)$_2$ (black) in the Zn(dedc)$_2$ + Sn(dedc)$_4$ + toluene solution. These amounts contain precisely a 2:1:1 Cu:Zn:Sn molar ratio (plus 20 parts sulfur, an excess of 16 moles per molecule), the ratio found in stoichiometric kesterite CZTS, though in practice, precursor conversion efficiency must be taken into account.

The Cu(dedc)$_2$ in particular is not fully soluble in toluene, but as long as the material is kept well-suspended in the precursor solution, it is uniformly distributed in the aerosol created by the nebulizer. To do this, the precursor solution is always allowed to ultrasonicate for at least 20 minutes before use, it is well-stirred before being added to the nebulizer jar, and it is kept under constant stirring while being nebulized.

The spray process, still, however, seems to be not totally efficient. The author has found that there are typically concentrated deposits of precursor left in the nebulizer after the completion of a run. This inefficiency eventually leads to non-

Figure 3.2.2: Elemental atomic percentages of copper, zinc, and tin in three CZTS powder samples made with varying amounts of precursors.
stoichiometric CZTS production. To compensate, though, the composition of the powder can be controlled by varying the relative precursor ratios (fig. 3.2.2). By increasing the amount of Cu(dedc)₂ relative to Zn(dedc)₂ and Sn(dedc)₄, for example, as seen in the figure, the resulting powder stoichiometry increases in copper relative to zinc plus tin (determined by energy dispersive x-ray analysis — EDS — in scanning electron microscopy —SEM). The optimal precursor ratio is not exceedingly consistent, but has been found to be roughly five parts Cu(dedc)₂ to two parts Sn(dedc)₄ to one part Zn(dedc)₂.

Doping of CZTS material can also be achieved by including various additives to the precursor solution. In particular, sodium diethyldithiocarbamate and silicon nanoparticles (separately) have been added to the generic mixture to induce sodium and silicon doping into CZTS nanoparticles.

3.3: Synthesizing CZTS Thin Films/Platelets

Figure 3.3.1: Aerosol spray pyrolysis system used to synthesize CZTS thin films.
To synthesize CZTS thin films, the spray pyrolysis apparatus is assembled as shown in fig. 3.3.1. The location of the substrate within the furnace allows for crystal nucleation and growth in one step, theoretically removing the need for an annealing step in a sulfur-rich atmosphere.

The precursor solution is aerosolized by the pressure differential caused by the flow of the carrier gas through the nebulizer head. In this apparatus, a one-jet nebulizer head is used, so the carrier gas (Ar) flow rate is limited to ~0.5 SCFH. The aerosol is then pulled through a focusing aperture (diameter of 1/8”) and directed onto a substrate, fastened onto a stainless steel mount. The excess non-decomposed precursor, carrier gas, and decomposed diethylidithiocarbamate complexes are then pulled through the furnace by a rotary vane vacuum pump, and filtered by a liquid nitrogen trap, before proceeding to an exhaust tube.

The system is kept at an ambient pressure of ~225 torr during runs, measured on both sides of the furnace. Molybdenum-coated soda lime glass is the substrate of choice, as it makes an effective base for a PV cell. Blank quartz can also be used in order to obtain absorption measurements on the films. The furnace is set within a range of 350-500 °C. Temperatures lower than this run the risk of not fully decomposing the precursors, while temperatures higher than this run the risk of damaging the molybdenum coating on the substrate. The location of the substrate within the furnace is variable. The system is typically run with the substrate a distance of ~45 cm away from the nebulizer
The substrate temperature is measured approximately by a thermocouple that is threaded through to touch the back side of the substrate mount. The substrate temperature is measured to be consistently 20 ºC below the ambient temperature of the furnace, which is attributed to the cooling effect of the aerosol and carrier gas colliding with the substrate.

The system is allowed to run until the nebulizer jar is empty, or as long as the user desires, depending on the desired thickness of the film. At the completion of a run, the carrier gas is stopped, the nebulizer is shut off from the furnace tube by a quarter-turn valve, and the furnace tube is pumped constantly until the furnace drops to a temperature below 300 ºC. The system is then opened, and the substrate is removed and the resulting film is characterized (see section 3.8).

3.4: Synthesizing CZTS Nanoparticles

![Diagram of aerosol spray pyrolysis system](image)

**Figure 3.4.1:** Aerosol spray pyrolysis system used to synthesize CZTS nanoparticles.
To synthesize CZTS nanoparticles, the spray pyrolysis apparatus is assembled as shown in fig. 3.4.1. The use of bubblers to collect the powder allows for operation at atmospheric pressure while keeping the system sealed from atmospheric gases.

The precursor solution is aerosolized by the pressure differential caused by the flow of the carrier gas through the nebulizer head. In this apparatus, a six-jet nebulizer head is used, the carrier gas (Ar) flow rate is set to ~12 SCFH for each run, which gives the aerosol droplets a residence time of 0.12 seconds in the thermal zone. The aerosol is then pushed into the tube furnace, where the thermal conditions are such that precursors decompose and form CZTS particles. The particles, along with the excess non-decomposed precursor, carrier gas, and decomposed diethyldithiocarbamate complexes are then pushed through two toluene-filled bubblers to separate the powder from gases. The solid material is left suspended in the bubblers.

At the end of a run, the material is washed five times with toluene and methanol to dissolve any diethyldithiocarbamate complexes or metal salts that may have formed and separated via centrifuge. The remaining particles are then dispersed in methanol and dried under argon flow. The material can then be characterized accordingly (see section 3.8).

During each run, the bubblers must be refilled with toluene as it evaporates in order to ensure good collection of solid material.

The optimal temperature at which to synthesize CZTS nanoparticles has been found to be 800 °C (see results in section 4.2). At lower temperatures, the mass of
particles recovered diminishes significantly, while at higher temperatures, the particles are found to be embedded in an amorphous matrix.

3.5: Doping CZTS Nanoparticles

The elemental composition of CZTS thin films and nanoparticles can be tuned based on the relative precursor ratios (fig. 3.2.2), meaning that the apparatus provides a highly controllable method of forming CZTS structures. Further experiments have been performed studying the controllability of dopants in CZTS nanoparticles.

To dope the nanoparticles with sodium, sodium diethyldithiocarbamate — having the same molecular structure to the primary precursors — is added to the precursor solution.

The more difficult dopant is silicon. The desired effect is to replace some of the tin lattice sites with silicon. To add silicon to the CZTS nanoparticles, some of the tin precursor is subtracted from the precursor solution, while some silicon nanoparticles (diameter of ~10 nm, formed by a non-thermal plasma method [3], stored in an oxygen free environment) are added.

3.6: Coating CZTS Dispersions onto Substrates

To create thin films from CZTS nanoparticles, it is necessary to coat the particles uniformly on a substrate. In this work, CZTS are sprayed onto substrates using a Master® airbrush.
The dry CZTS nanoparticles are well-dispersed in methanol by ultrasonicating for >15 minutes. The solution is then added to the airbrush cup, and is turned into an aerosol, and sprayed onto a substrate. Compressed argon (99.97% pure) is used to generate the aerosol. To achieve a uniform coating, it is necessary to run the carrier gas at a low flow rate; here ~1 SCFH is used. The spray is directed onto a masked substrate in a uniform pattern until the desired thickness is achieved. It takes between 45 minutes and one hour to obtain a 1 µm-thick film. An exemplary coating is shown in fig. 3.6.1, both on the macro and micro scale.

Thus far, the coatings have been laid on a thermally oxidized silicon wafer, to allow easy characterization. In the future, the coatings will be applied to quartz, and molybdenum-coated soda lime glass for optical characterization and cell fabrication. The substrate is masked over a rectangular area using masking tape, which also serves to hold the substrate immobile and level. The substrate is also made twice as large as the desired film area, and is pre-scored. This is to allow easy splitting of the substrate and coating to give a control sample, as well as one that will be annealed.

Figure 3.6.1: Macroscopic, SEM top down, and SEM cross section images of a coating of CZTS nanoparticles created using the process outlined in section 3.6.
3.7: Sintering CZTS Nanoparticles to form Crystalline Films

Once the CZTS nanoparticles have been coated onto a substrate, the sample must be baked in a sulfur-rich atmosphere to promote crystal grain formation and growth, as discussed in Section 2.7. To do this, the samples are sealed in an evacuated ampoule with some solid sulfur, and then placed inside a tube furnace for a designated duration.

The samples are placed in a 1/4” diameter quartz tube, with one end that has been closed off. Approximately 12 mg of sulfur are also added the tube, which when heated to 500 °C — the boiling point of sulfur is 444.61 °C [4] — will yield roughly atmospheric sulfur pressure (~700 torr) within the sealed and evacuated ampoule.

The quartz tube is then joined to an airtight apparatus via a Swagelok Ultra-Torr fitting to be pumped down to ~10^-5 torr by a roughing rotary vane pump, and then a turbo-molecular pump (fig 3.7.1a). The ampoule is then closed off from the system by a

Figure 3.7.1: a) Shows an ampoule loaded with sample and elemental sulfur after pumping down to 10^-5 torr. b) Shows an ampoule that has been sealed off to be eight inches long from image a. c) Shows an ampoule that has undergone the annealing procedure. Note the white deposit on the left side of the ampoule, that is the re-condensed sulfur. The light background on the right of image c has been added for contrast.
quarter-turn valve. The ampoule plus valve assembly is then removed from the apparatus and the ampoule is then sealed off so that it is eight inches long using an oxyacetylene torch.

The sealed ampoule is then inserted into a 500 °C preheated 1-inch tube furnace and baked for 30 minutes. At the end of the bake, the ampoule is moved so that one end is slightly outside the furnace, while the end with the samples are still predominantly within the heating zone in the furnace. This allows the exposed end to cool more quickly, and thus the sulfur vapor condenses and solidifies away from the samples (fig 3.7.1c).

Upon cooling to below the boiling point of sulfur (444.7 °C), the ampoule can be removed and allowed to cool uniformly in the ambient environment. Here, the ampoule is not removed from the furnace until it has cooled to below 300 °C to give less probability of sulfur condensing on the samples. Once cooled, the ampoule is broken open and the samples are removed and characterized.
3.8: References


Chapter 4: Results

4.1: Synthesis of CZTS Thin Films/Platelets

We have demonstrated that spray pyrolysis is not an effective method to synthesize CZTS thin films, and disseminated our results in [1]. Effectively, at low temperatures (~350-400ºC), the film does not deposit much at all, likely due to the incomplete decomposition of the precursors. At higher temperatures, the deposited material nucleates non-uniformly, particularly above ~440 ºC, at which point two-dimensional platelet structures nucleate above the substrate (fig. 4.1.1).

The dominant variable associated with the structure and morphology of these films is temperature. Within a small temperature range (~350-500 ºC), there is an immense morphological development, ranging from a film of negligible thickness grown at 350 ºC, to a very complex morphological structure that is made up of two-dimensional
platelet structures in a disorderly arrangement that increases the effective film thickness to 5-10 µm seen in films grown above 440 ºC.

This same apparatus and procedure has also been used to synthesize binary copper sulfide, tin sulfide, and zinc sulfide films. From these films, we attribute the platelet formation and nucleation to the presence of a copper sulfide phase. For tin sulfide and zinc sulfide films, nanostructured isotropic growth is observed. It is only in copper sulfide films where anisotropic growth is observed (fig. 4.1.2).

Films synthesized at various temperatures within this growth range have been characterized extensively. XRD scans of

![Figure 4.1.2: SEM micrographs of a) zinc sulfide, b) tin sulfide, and c) copper sulfide samples grown on molybdenum-coated soda lime glass each at 450 ºC.](image)

![Figure 4.1.3: (From [1]) a) XRD of the sample grown at 460 ºC (see fig. 4.1.1). b) UV-vis absorbance for the sample grown at 460 ºC. The Tauc plot generated using the spectrum is shown in the inset.](image)
a sample with a prevalence of the two-dimensional platelet structures indicates the presence of kesterite-phase CZTS, while photospec. measurements allow the determination of the material’s band gap, found to be \( \sim 1.5 \) eV (fig. 4.1.3). While the characteristic kesterite CZTS peaks in XRD match well with values reported in literature, the spectrum by itself is inconclusive proof, as it matches well with spectral peaks for other binary and ternary sulfides, like ZnS and Cu\(_2\)SnS\(_3\) [2]. In combination with Raman, though, it is easier to be conclusive about the phase of the material.

Raman spectroscopy of samples grown across the 350-500 °C temperature range shows an interesting development as temperature is increased. At the lower temperatures (360, 400 °C), the Raman spectra show the presence of crystalline CZTS, but also molybdenum sulfide (MoS\(_2\)), suggesting that some of the precursors have decomposed, but the most thermodynamically favorable reaction is with the molybdenum substrate, instead of the other metal ions present. At the higher temperatures (440, 460 °C), the Raman spectra show the

![Figure 4.1.4: (From [1]) Thin film Raman spectra as a function of temperature.](image)
disappearance of the MoS$_2$ peak, as well as narrower and more well defined — meaning more crystalline — CZTS peaks at 288, 338, and 380 cm$^{-1}$ (fig. 4.1.4).

Elemental analysis of large areas on these films shows further support to the hypothesis that at the lower temperatures, the failure of film growth is due to the lack of precursor decomposition. Noting that the highest precursor decomposition temperature is 334 ºC for Zn(dedc)$_2$, at lower temperatures, there is an excess of copper — the precursor for which has the lowest decomposition temperature at 302 ºC. At higher temperatures,

<table>
<thead>
<tr>
<th>T (ºC)</th>
<th>At. % Cu</th>
<th>At. % Zn</th>
<th>At. % Sn</th>
<th>At. % S</th>
<th>$[\text{Cu}] / [\text{Zn}] + [\text{Sn}]$</th>
<th>$[\text{Zn}] / [\text{Sn}]$</th>
</tr>
</thead>
<tbody>
<tr>
<td>360</td>
<td>38.1(±1.6)</td>
<td>15.5(±0.6)</td>
<td>6.8(±0.5)</td>
<td>39.5(±2.0)</td>
<td>1.70</td>
<td>2.2</td>
</tr>
<tr>
<td>400</td>
<td>34.8(±0.8)</td>
<td>21.9(±0.5)</td>
<td>8.7(±0.3)</td>
<td>35.4(±1.6)</td>
<td>1.13</td>
<td>2.5</td>
</tr>
<tr>
<td>440</td>
<td>25.7(±0.8)</td>
<td>25.0(±0.7)</td>
<td>9.5(±0.5)</td>
<td>39.7(±1.9)</td>
<td>0.75</td>
<td>2.6</td>
</tr>
<tr>
<td>460</td>
<td>29.8(±1.0)</td>
<td>21.0(±0.6)</td>
<td>10.5(±0.4)</td>
<td>38.7(±1.6)</td>
<td>0.94</td>
<td>2.0</td>
</tr>
</tbody>
</table>

Table 4.1.1: (From [1]) Summary of the results from the elemental analysis performed by EDS on samples grown at different temperatures. The values correspond to atomic percentages and to their ratios.

Figure 4.1.5: (From [1]) (a) TEM of a nanoplatelet grown at 460 ºC. EDS scans and selected area diffraction pattern for two spots are also shown. (b) Elemental mapping for the platelet in (a) showing the variation in the local composition.
the $[\text{Cu}]/([\text{Zn}]+[\text{Sn}])$ ratio levels out to $\sim 1$, which is ideal for stoichiometric CZTS (table 4.1.1). The elemental analysis was performed on areas $\sim 100 \, \mu\text{m}$ square, meaning that any phase instability on individual platelets is inconsequential.

Elemental analysis has also been performed on individual platelets in TEM (fig. 4.1.5). The platelets are clearly crystalline, though the diffraction pattern suggests that multiple phases are present within a single platelet. Elemental mapping suggests that the bulk of the platelets could be kesterite CZTS, while the phase impurity is focused on the edges, where an excess of copper relative to zinc and tin is seen.

It is hypothesized that the copper sulfide has a chance to nucleate as a binary sulfide because the corresponding precursor has the lowest decomposition temperature. Once the copper sulfide has nucleated, it is thermodynamically stable, and will not change phase, though it appears to catalyze the formation of anisotropic platelet growth and the formation of kesterite CZTS.

While interesting, these findings suggest that spray pyrolysis is an ineffective method for synthesizing CZTS thin films for PV applications. In order to make an effective PV, it is necessary for the interface between each layer to have exceptional contact, so that little charge is lost between the different materials. Since the inherent problem with the application of the CZTS material system to PVs lies in charge loss and defects within the material, an alternative method of CZTS synthesis — nanoparticle formation and sintering — has been explored.
4.2: Synthesis of CZTS Nanoparticles

Using aerosol spray pyrolysis to synthesize CZTS nanoparticles appears to be more advantageous than using the process to synthesize CZTS films, mainly due to its economic and scalable application to the technology’s marketability. The process can be separated into a few distinct steps to go from

Figure 4.2.1: (a) TEM of a nanoparticle grown at 800 ºC. Inset provided to better observe uniform crystal fringes. (b) Diffraction pattern of particle shown in (a), three primary fringes align well with primary kesterite-CZTS peaks.

Figure 4.2.2: (a) Shows an XRD spectrum of nanoparticles grown at 800 ºC and (b) Raman spectrum of same nanoparticles.
precursor material through to uniform, crystalline CZTS thin films. Discussed here are results found when attempting to synthesize and control the composition of CZTS nanoparticles.

We have shown the ability to consistently create crystalline kesterite-CZTS nanoparticles with a narrow size distribution centered around ~20 nm in diameter (fig. 4.2.1). Further characterization of these particles via XRD and Raman confirms the presence of kesterite-phase CZTS (fig. 4.2.2).

With the ability to create nanocrystalline CZTS confirmed, the controllability of the system needed to be assessed. To do this, the system was run with one parameter variable at a time. A study of the effect of running at different furnace temperatures and of using altered precursor ratios in the precursor solution (i.e. the amount of Cu(dedc)$_2$ relative to Zn(dedc)$_2$ and Sn(dedc)$_4$).

By running the system at temperatures from as low as 400 °C to as high as 1,000 °C, it was determined that the optimal running temperature is approximately 800 °C, and so has been settled on as the standard operating temperature for the system.

Below this optimal temperature, there is a marked decline in the amount of powder produced and collected, implying that the precursor doesn’t fully decompose fully at lower temperatures. While the furnace is set above the decomposition temperature for all three precursors even at 400 °C, the residence time of the aerosol droplets within the furnace is too short (~0.12 s) to allow an adequate amount of thermal energy to be radiated into the droplets to cause decomposition of the precursors, hence the high
temperature is necessary. The crystalline powder collected is still indicated to be kesterite-CZTS by Raman (fig. 4.2.3).

Above the optimal 800 ºC temperature, the powder is still formed as crystalline CZTS, but TEM indicated the powder is embedded in an amorphous matrix (fig. 4.2.4). Cursory analysis via Fourier Transform Infrared Spectroscopy indicates that the amorphous material is likely organic in composition, making it undesirable for the material system.

Then, by running the spray pyrolysis system with variable relative precursor ratios, the controllability of the material composition has been examined. The material
stoichiometry has been shown to be highly controllable, though it is clear that the system is incapable of perfectly converting all of the precursor into CZTS effectively, as observed in Table 4.2.1 — a summary of EDS analysis performed on powder formed with varied precursor concentrations.

Perfect precursor conversion would achieve the ideal relative copper : zinc : tin ratio with a relative Cu(dedc)$_2$ : Zn(dedc)$_2$ : Sn(dedc)$_4$ mass ratio of approximately 2:2:1 (used in Sample 1 of table 4.2.1). However, ideal CZTS stoichiometry was approached as both tin and zinc precursors were decreased relative to copper precursor, implying the copper precursor is more difficult to convert than the others. This is likely due to the fact that Cu(dedc)$_2$ has been observed to be imperfectly soluble in toluene, so there is a depletion of this precursor in the aerosol droplets unless it’s concentration is increased.

This data provides evidence that the aerosol spray pyrolysis system described here is capable of controllably producing phase-pure kesterite-CZTS.

<table>
<thead>
<tr>
<th></th>
<th>Cu(dedc)$_2$</th>
<th>Sn(dedc)$_4$</th>
<th>Zn(dedc)$_2$</th>
<th>At. % Cu</th>
<th>At. % Zn</th>
<th>At. % Sn</th>
<th>$\frac{[Cu]}{[Zn]+[Sn]}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>S1</td>
<td>500 mg</td>
<td>500 mg</td>
<td>250 mg</td>
<td>25.59</td>
<td>34.62</td>
<td>39.79</td>
<td>0.34</td>
</tr>
<tr>
<td>S2</td>
<td>500 mg</td>
<td>340 mg</td>
<td>180 mg</td>
<td>35.96</td>
<td>35.16</td>
<td>28.88</td>
<td>0.56</td>
</tr>
<tr>
<td>S3</td>
<td>500 mg</td>
<td>180 mg</td>
<td>90 mg</td>
<td>42.87</td>
<td>31.60</td>
<td>35.53</td>
<td>0.63</td>
</tr>
</tbody>
</table>

Table 4.2.1: Summary of the results from the EDS performed on samples grown from different precursor ratios.
4.3: Doping of CZTS Nanoparticles

Sodium is a common dopant in the CIGS and CZTS systems [3, 4]. In CZTS, Johnson et al showed that crystal grain size increased when annealing films of cosputtered copper, zinc and tin on a soda lime glass (SLG) substrate in a sulfur rich atmosphere as opposed to a quartz or pyrex glass substrate [4]. The conclusion made is that impurities in the SLG — particularly alkali metals — diffuse into the CZTS film and drive crystal grain growth, which is a potential factor in PV conversion efficiency.

It stands to reason that the presence of these alkali metals, namely sodium, in CZTS nanoparticles will drive the growth of large crystal grains during annealing. Results suggesting as much have been shown by Chernomordik et al in [5].

The method of doping sodium into CZTS in [4] and [5] relied on diffusion from external sources, namely SLG substrates or coatings of alkali hydroxides on ampoule surfaces. The ability to more controllably dope sodium into the system without relying on a particular substrate would allow the crystal grain growth effect to be better studied and understood.

Preliminary data

![Figure 4.3.1: Chart showing amount of sodium relative to copper, zinc and tin in powder grown with varying amounts of Na(dedc) mixed in with precursor solution characterized by EDS. Sample 1: 0 mg; Sample 2: 25 mg; Sample 3: 50 mg; Sample 4: 250 mg. Note the vertical scale is logarithmic.](image)
shows the ability to controllably dope sodium into CZTS nanoparticles via aerosol spray pyrolysis. The experimental parameters, described in section 3.5 are simple. Samples were grown at 800 °C using 500 mg Cu(dedc)₂, 180 mg Sn(dedc)₄, 90 mg Zn(dedc)₂, plus 0, 25, 50, or 250 mg Na(dedc). The resulting powder was then characterized by EDS, and the results are shown in Fig. 4.3.1. Further analysis is required to determine whether the sodium is truly incorporated into the CZTS lattice, and whether or not the result is repeatable, but the data already collected suggests that the amount of sodium incorporated into the powder is simply dependent on the amount of sodium precursor in the precursor solution, as might be expected.

Doping silicon into CZTS is a much more experimental idea. In 1987, Chen et al at Boeing added gallium as a dopant to the copper-indium-selenide system [6]. The dopant gallium increased the photo-conversion efficiency of the material up to 10.1% a marked improvement on previous iterations, and spawned the CIGS system, which has been further improved and commercialized since.

This lattice-replacement doping mechanism — replacing a large Group III atom with a smaller atom from the same column in the periodic table — could also potentially be viable in the CZTS system. We propose replacing some of the tin in the kesterite-CZTS with the much smaller silicon — both being group IV elements.

The mechanism for introducing silicon via the same spray pyrolysis apparatus is outlined in section 3.5. The challenge would be to reach a thermal region where the silicon nanoparticles can be dissociated and incorporated into the CZTS matrix.
Preliminary XRD characterization of particles grown with decreasing amounts of tin precursor and increasing amounts of silicon nanoparticles is shown in Fig. 4.3.2. An attempt was made to account for the inefficiency of the precursor-to-powder conversion of the apparatus, so more silicon and tin precursor were added than necessary to achieve the attempted silicon and tin combined concentrations in the final powder. It is apparent that the CZTS spectrum, seen in 4.3.2a, is affected by subtracting tin and adding silicon, though it is difficult to determine whether or not the silicon is truly incorporated into the kesterite lattice without further characterization of this powder — primarily Raman and TEM. The spectrum seen in 4.3.2e could just be a combination of the kesterite and silicon characteristic spectra.
In short, the aerosol spray pyrolysis in discussion here shows the potential to be able to controllably introduce a variety of dopants to CZTS nanoparticles.

4.4: CZTS Nanoparticle Annealing

Preliminary efforts have been made to sinter CZTS nanoparticles into uniform, large-crystal-grained films. Using the process outlined in section 3.7, several attempts have been made to coat and anneal CZTS nanoparticles made via the spray pyrolysis system.

The coatings (fig. 3.6.1) come out uniformly and consistently, though the thickness is hard to control as the coating duration is somewhat arbitrary, and the efficiency of coating the powder via the airbrush is unknown.

The results to this point haven’t been exceedingly positive. In general, the films are annealed for 30 minutes at 500 °C with 0.5-1 atm of sulfur pressure inside the ampoule (similar to Figure 4.4.1: Shows top down (a) and cross section (b) SEM images of annealed CZTS sample with segregated structures observed on the surface of the film.)
However, there are large two-dimensional structures that diffuse out of the film and form on the surface of the film, as seen in Fig. 4.4.1.

By EDS elemental mapping, it is apparent that these segregated structures must be some form of tin sulfide (fig. 4.4.2). The presence of tin is concentrated in the areas where the structures are present (fig. 4.4.2 spots 1 and 2 in d) and e)), while at the same time there is a deficiency of copper and zinc in those same areas (fig. 4.4.2 spots 1 and 2 in b) and c)).

More work needs to be done to determine the optimal conditions to form a uniform, large-grained CZTS film from a coating of CZTS nanoparticles. This is an integral step in fabricating thin film PVs, and current research in the field indicates that
decreasing the defect and impurity concentrations in the p-type layer is crucial to
achieving high photo-conversion efficiency (see section 2.3).
4.5: References


Chapter 5: Conclusions/Recommendations

5.1: Conclusions

Solar energy, along with other renewable source-based energy, is projected to play a large part in our domestic power generation within the next half-century. The effort to decrease PV system cost comes in part from decreasing the processing and material costs of fabricating a PV module itself, from reducing other costs associated with tying the power generation to the electricity grid, and also from human costs, like installing, permitting, and inspecting PV systems. In the roughly sixty years that PVs have been sold commercially, these costs have already been dramatically slashed via important technological innovations to PV module fabrication. Thick single crystal silicon-based PVs have given way to thin film PVs, which in the future will give way to sustainable material-based thin film PVs, such as CZTS. By working to further increase the affordability of small-scale residential PV systems as well as large-scale industrial PV systems, the growth of the sector will be stimulated at the expense of non-renewable energy sources like coal, oil, or natural gas.

Currently, CZTS as a thin film PV absorber layer is not technologically ready to be introduced in a commercial market, as the photo-conversion efficiency of even the best lab-scale devices is incomparable to other technologies, like crystalline silicon, CIGS, or CdTe. Recent efforts have also focused on synthesizing CZTS absorber layers in a more inexpensive and industrially scalable manner. Recent work has been done synthesizing both thin films and nanoparticles, which can be sintered into thin solid films.
One such method of synthesizing CZTS thin films and nanoparticles — presented here — is via spray pyrolysis.

While spray pyrolysis has been previously studied as a method of synthesizing CZTS thin films using single-source diethyldithiocarbamate precursors by other groups, it has not been shown conclusively to be an effective method of doing so. We similarly conclude that the crystallinity of said films is poor, and the film material is not phase-pure. Further, we hypothesize that the separation of platelet structures above the surface of the sprayed thin films suggests a copper sulfide phase impurity acts as a catalyst for non-uniform morphological development.

Our work suggests that spray pyrolysis synthesis of CZTS nanoparticles using single-source diethyldithiocarbamate precursors is a more viable method of forming CZTS by this process. We find the composition and crystallinity to be consistent with kesterite CZTS formed by other methods. Further, we show the composition to be tunable simply by adjusting the relative precursor ratios in the precursor solution. The process also shows promise in being able to controllably dope the powder with sodium or silicon by adding material to the precursor solution. Our current efforts are focused on determining the optimal conditions by which to sinter these nanoparticles into large-crystal grain thin films, which can then be used as the absorber layer in a PV cell, the ultimate goal of this project.
5.2: Future Work

Short term progression of this work will focus on material innovation and optimization, particularly involved with the doping of CZTS, preliminary results for which are outlined in Section 4.3. The benefits of incorporating either sodium or silicon as replacement or interstitial defects in the kesterite CZTS lattice are as yet unclear. The ability to controllably achieve uniform material doping with these materials, however, allow the opportunity to understand any effects, positive or negative, on photovoltaic performance.

In the long term, this project will continue in developing infrastructure to be able to fabricate working PV devices based on the CZTS material made by the process outlined here. The integral steps for this progression include optimizing the nanoparticle sintering process outlined in Section 4.4. This includes determining the appropriate nanoparticle stoichiometry, sulfur vapor pressure, sintering temperature, and sintering duration to achieve a uniform, large-crystal grain, stoichiometrically accurate thin film. Beyond this will come the optimization of the heterojunction partner to the photo-absorber layer — a thin n-type layer. Eventually a full photovoltaic cell can be constructed based on this absorber-emitter heterojunction structure.